

**Vishay Siliconix** 

# Dual P-Channel 12-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω)	I <sub>D</sub> (A)		
	0.042 at V <sub>GS</sub> = - 4.5 V	- 6.5		
- 12	0.058 at V <sub>GS</sub> = - 2.5 V	- 5.5		
	0.082 at V <sub>GS</sub> = - 1.8 V	- 1.2		

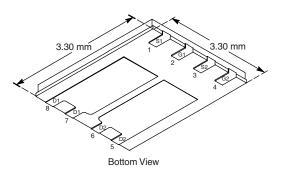
#### PowerPAK 1212-8

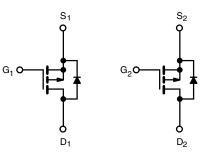
#### **FEATURES**

- Halogen-free Option Available
- TrenchFET<sup>®</sup> Power MOSFET: 1.8 V Rated

#### **APPLICATIONS**

- · Load Switch
- PA Switch
- Battery Switch
- **Bi-Directional Switch**





P-Channel MOSFET

P-Channel MOSFET

**Steady State** 

Ordering Information: Si7925DN-T1-E3 (Lead (Pb)-free) Si7925DN-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T<sub>A</sub> = 25 °C, unless otherwise noted Symbol 10 s

Drain-Source Voltage		V <sub>DS</sub>	- 12		v	
Gate-Source Voltage		V <sub>GS</sub>	± 8			
Continuous Drain Current (T 150 °C)a	T <sub>A</sub> = 25 °C	– I <sub>D</sub>	- 6.5	- 4.8		
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 85 °C		- 4.7	- 3.4	1	
Pulsed Drain Current		I <sub>DM</sub>	- 20		A	
Continuous Source Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	- 2.1	- 1.1		
	T <sub>A</sub> = 25 °C	– P <sub>D</sub>	2.5	1.3	w	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 85 °C		1.5	0.69	vv	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature) <sup>b, c</sup>			260			

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum handling to Angling 18	t ≤ 10 s	R <sub>thJA</sub>	40	50	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		75	94	°C/W
Maximum Junction-to-Case	Steady State	R <sub>thJC</sub>	5.6	7	

Notes:

Parameter

a. Surface Mounted on 1" x 1" FR4 board.

b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

Unit

COMPLIANT

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<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions Min.		Тур.	Max.	Unit		
Static			_					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -250 \ \mu A$	- 0.40		- 1.0	V		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0$ V, $V_{GS} = \pm 8$ V			± 100	nA		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -12 \text{ V}, V_{GS} = 0 \text{ V}$			- 1	μΑ		
		$V_{DS}$ = - 12 V, $V_{GS}$ = 0 V, $T_{J}$ = 85 °C			- 5			
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$ - 20				А		
Drain-Source On-State Resistance <sup>a</sup>		$V_{GS}$ = - 4.5 V, I <sub>D</sub> = - 6.5 A		0.033	0.042	Ω		
	R <sub>DS(on)</sub>	$V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -5.5 \text{ A}$		0.046	0.058			
		V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 1.2 A		0.065	0.082			
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = -6 V, I_{D} = -6.5 A$		19		S		
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = - 2.1 A, V <sub>GS</sub> = 0 V		- 0.8	- 1.2	V		
Dynamic <sup>b</sup>								
Total Gate Charge	Qg			11	12			
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = - 6 V, $V_{GS}$ = - 4.5 V, $I_{D}$ = - 6.5 A		1.7		nC		
Gate-Drain Charge	Q <sub>gd</sub>			2.8				
Gate Resistance	Rg			8.2		Ω		
Turn-On Delay Time	t <sub>d(on)</sub>			20	30			
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 6 V, $R_L$ = 6 $\Omega$		50	75	ns		
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D}\cong$ - 1 A, $\text{V}_\text{GEN}$ = - 4.5 V, $\text{R}_\text{G}$ = 6 $\Omega$		70	105			
Fall Time	t <sub>f</sub>			50	75			
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 2.1 A, dI/dt = 100 A/μs		41	80			

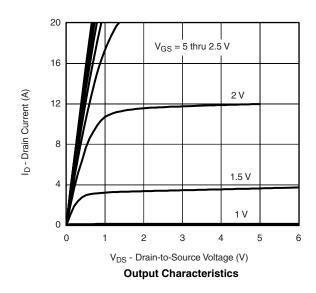
Notes:

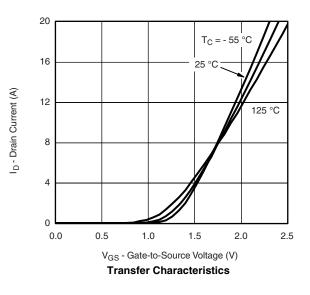
a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



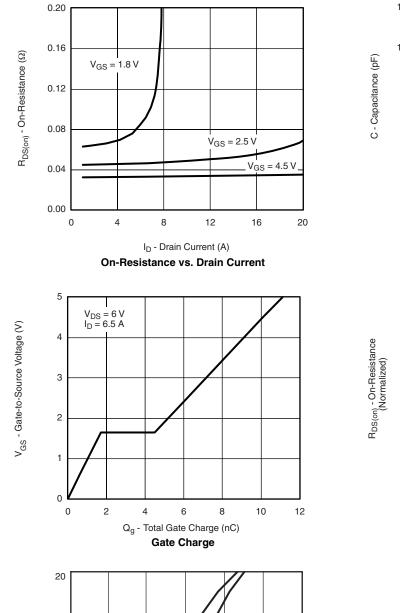


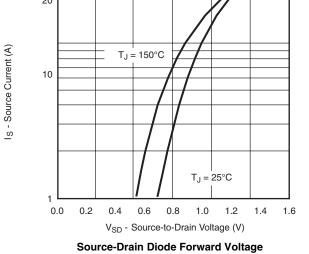


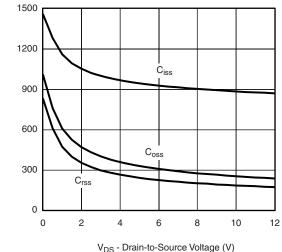
# Si7925DN

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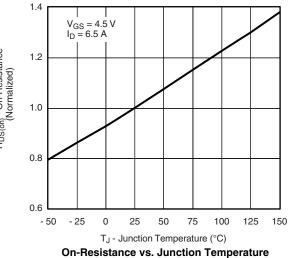
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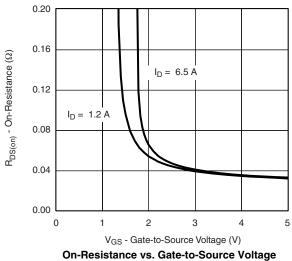






Capacitance

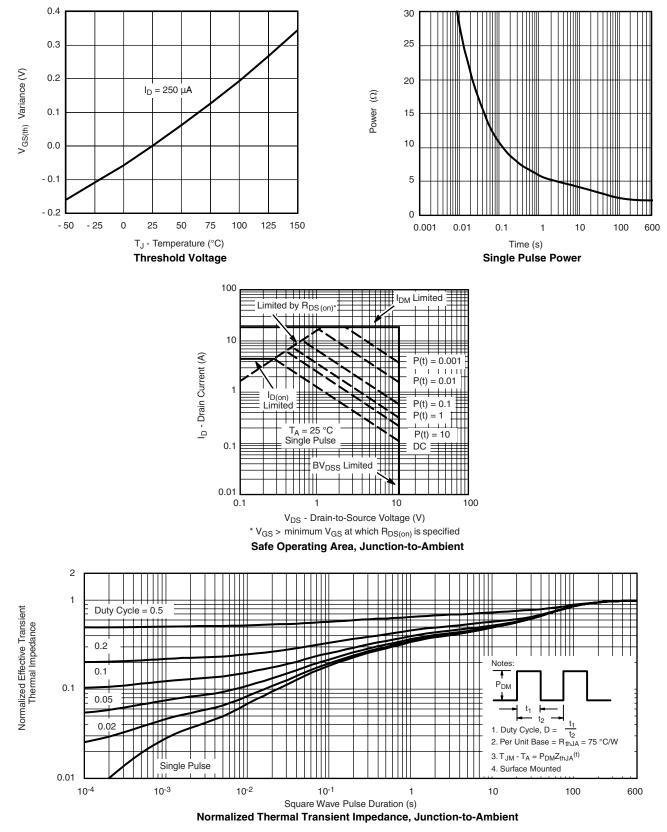




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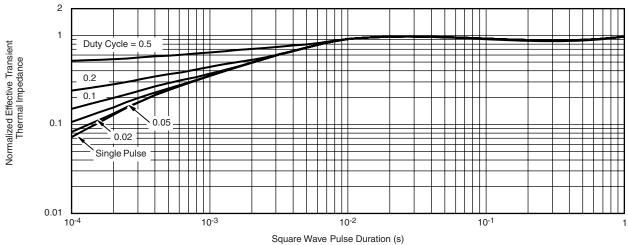




Si7925DN

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### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?72343.



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